CMOS Digital Integrated Circuits Silicon Monolithic

TC7WB66CFK,TC7WB67CFK

1. Functional Description

• Dual SPST Bus Switch

2. General

The TC7WB66CFK and TC7WB67CFK are low ON-resistance, high-speed CMOS 2-bit bus switches. These bus switches allow connections or disconnections to be made with minimal propagation delay while maintaining Low power dissipation which is the feature of CMOS.

TC7WB66CFK requires the output enable (OE) input to be set low to place the output into the high impedance state, whereas the TC7WB67CFK requires the output enable (\overline{OE}) input to be set high to place the output into the high impedance.

 $These \ Bus \ switches \ consist \ of \ P-MOS \ and \ N-MOS \ structure, \ meaning \ these \ devices \ are \ suitable \ for \ analog \ signal \ transmission.$

All inputs are equipped with protector circuits to protect the device from static discharge.

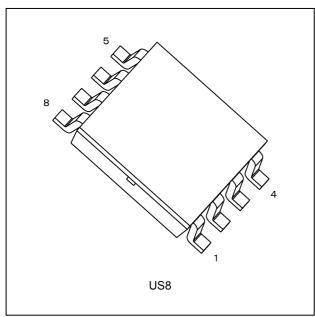
3. Features

- (1) AEC-Q100 (rev.H) Grade 1 qualified (Note 1)
- (2) Wide operating temperature range: $T_{opr} = -40$ to 125 °C (Note 2)
- (3) Operating voltage: V_{CC} = 1.65 to 5.5 V
- (4) ON capacitance: $C_{I\!/\!O}$ = 10 pF Switch On (typ.) $@V_{CC}$ = 5.0 V
- (5) ON resistance: $R_{ON} = 4 \Omega$ (typ.) $@V_{CC} = 4.5 V$, $V_{IS} = 0 V$
- (6) Package: US8

Note 1: This device is compliant with the reliability requirements of AEC-Q100. For details, contact your Toshiba sales representative.

Note 2: For devices with the ordering part number ending in (CT. T_{opr} = -40 to 85 °C for the other devices.

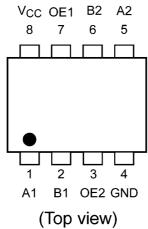
4. Packaging



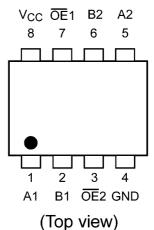
Start of commercial production 2020-09 2021-03-05

5. Pin Assignment

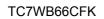
TC7WB66CFK

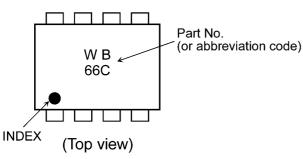


TC7WB67CFK



6. Marking



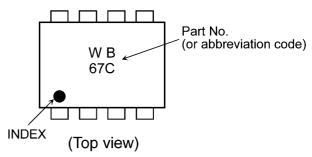


TC7WB67CFK

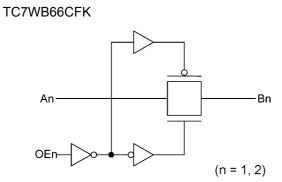
TC7WB67CFK

An

OEn



7. Block Diagram



8. Principle of Operation

8.1. Truth Table

Inputs OE (TC7WB66CFK)	Inputs OE (TC7WB67CFK)	Function
Н	L	A port = B port
L	Н	Disconnect

Bn

(n = 1, 2)

9. Absolute Maximum Ratings (Note) (Unless otherwise specified, $T_a = 25$ °C)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V _{CC}		-0.5 to 7.0	V
Input voltage (OE, OE)	V _{IN}		-0.5 to 7.0	
Switch I/O voltage	Vs		-0.5 to V _{CC} +0.5	
Clamp diode current	I _{IK}		-50	mA
Switch I/O current	I _S		50	
Power dissipation	PD		200	mW
V _{CC} /ground current	I _{CC} /I _{GND}		±100	mA
Storage temperature	T _{stg}		-65 to 150	C°

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

10. Operating Ranges (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V _{CC}		1.65 to 5.5	V
Input voltage (OE, OE)	V _{IN}		0 to 5.5	
Switch I/O voltage	Vs		0 to V _{CC}	
Operating temperature	T _{opr}	(Note 1)	-40 to 125	°C
		(Note 2)	-40 to 85	
Input rise time	dt/dv		0 to 10	ns/V
Input fall time	dt/dv		0 to 10	

Note: The operating ranges must be maintained to ensure the normal operation of the device.

Unused control inputs must be tied to either V_{CC} or GND.

Note 1: For devices with the ordering part number ending in (CT.

Note 2: For devices except those with the ordering part number ending in (CT.

11. Electrical Characteristics

11.1. DC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C)

Characteristics	Part Number	Symbol	Note	Test Condition	V _{CC} (V)	Min	Тур.	Мах	Unit							
High-level input voltage		V _{IH}		—	1.65 to 1.95	$0.8 \times V_{CC}$	_	_	V							
(OE, <u>OE</u>)					2.3 to 5.5	$0.7\times V_{CC}$	_	—								
Low-level input voltage		V _{IL}		—	1.65 to 1.95	—	_	$0.2 \times V_{CC}$								
(OE, OE)					2.3 to 5.5	_	_	$0.3 \times V_{CC}$								
Input leakage current (OE, OE)		I _{IN}		V _{IN} = 0 to 5.5 V	1.65 to 5.5	_		±1.0	μA							
Switch OFF-state leakage current	TC7WB66- CFK	I _{SZ}		A, B = 0 to V _{CC} , OE = GND	1.65 to 5.5	—	_	±10								
	TC7WB67- CFK			$\frac{A, B = 0 \text{ to } V_{CC}}{OE} = V_{CC}$	1.65 to 5.5	—	_	±10								
	(Note 1), (Note 2)	V _{IS} = 0 V, I _{IS} = 30 mA	4.5	—	4	7	Ω									
							V _{IS} = 2.4 V, I _{IS} = 30 mA	4.5	—	5	12					
				V _{IS} = 4.5 V, I _{IS} = 30 mA	4.5	—	6	10								
				V _{IS} = 0 V, I _{IS} = 24 mA	3.0	—	5	9								
											V _{IS} = 3.0 V, I _{IS} = 24 mA	3.0	—	7	14	
						V _{IS} = 0 V, I _{IS} = 8 mA	2.3	—	6	12						
				V _{IS} = 2.3 V, I _{IS} = 8 mA	2.3	—	9	18								
				V _{IS} = 0 V, I _{IS} = 4 mA	1.65	—	8	20								
				V _{IS} = 1.65 V, I _{IS} = 4 mA	1.65	—	15	30								
Quiescent supply current		I _{CC}		$V_{IN} = V_{CC}$ or GND, $I_{OUT} = 0 A$	5.5	—		10	μA							
		Δl _{CC}		V _{IN} = V _{CC} - 0.6 V	5.5	—		50]							

Note 1: All typical values are at $T_a = 25$ °C.

Note 2: Measured by the voltage drop between A and B pins at the indicated current through the switch. On-resistance is determined by the lower of the voltages on the two (A or B) pins.

11.2. DC Characteristics (Unless otherwise specified, $T_a = -40$ to 125 °C)

Characteristics	Part Number	Symbol	Note	Test Condition	V _{CCB} (V)	Min	Тур.	Max	Unit
High-level input voltage		V _{IH}		—	1.65 to 1.95	$0.8\times V_{CC}$	_	—	V
(OE, OE)					2.3 to 5.5	$0.7\times V_{CC}$	_		
Low-level input voltage		V _{IL}		—	1.65 to 1.95	—		$0.2 \times V_{CC}$	
(OE, <u>OE</u>)					2.3 to 5.5	—	—	$0.3 \times V_{CC}$	
Input leakage current (OE, OE)		I _{IN}		V _{IN} = 0 to 5.5 V	1.65 to 5.5	—	—	±2.0	μA
Switch OFF-state leakage current	TC7WB66- CFK	I _{SZ}		A, B = 0 to V _{CC} , OE = GND	1.65 to 5.5	—	—	±20	
	TC7WB67- CFK			$\frac{A, B = 0 \text{ to } V_{CC}}{OE} = V_{CC}$	1.65 to 5.5	_	—	±20	
ON-resistance		R _{ON}	(Note 1), (Note 2)	V _{IS} = 0 V, I _{IS} = 30 mA	4.5	_	4	9	Ω
				V _{IS} = 2.4 V, I _{IS} = 30 mA	4.5	—	5	14	
				V _{IS} = 4.5 V, I _{IS} = 30 mA	4.5	—	6	12	
				V _{IS} = 0 V, I _{IS} = 24 mA	3.0	—	5	11	
				V _{IS} = 3.0 V, I _{IS} = 24 mA	3.0	—	7	16	
				V _{IS} = 0 V, I _{IS} = 8 mA	2.3	—	6	15	
				V _{IS} = 2.3 V, I _{IS} = 8 mA	2.3	_	9	21	
				V _{IS} = 0 V, I _{IS} = 4 mA	1.65	—	8	23	
				V _{IS} = 1.65 V, I _{IS} = 4 mA	1.65	—	15	33	
Quiescent supply current		I _{CC}		$V_{IN} = V_{CC}$ or GND, $I_{OUT} = 0 \text{ A}$	5.5	—	_	100	μA
		ΔI_{CC}		V _{IN} = V _{CC} - 0.6 V	5.5	—	_	100	

Note 1: All typical values are at T_a = 25 °C.

Note 2: Measured by the voltage drop between A and B pins at the indicated current through the switch. On-resistance is determined by the lower of the voltages on the two (A or B) pins.

11.3. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C)

Characteristics	Symbol	Note	Test Condition	V _{CC} (V)	Min	Max	Unit
Output enable time	t _{PZL} ,t _{PZH}		See Fig. 11.2.1, 11.2.2,		—	4	ns
			Table 11.2.1	$\textbf{3.3}\pm\textbf{0.3}$	_	6	
			$\textbf{2.5}\pm\textbf{0.2}$		9		
				1.8 ± 0.15		18	
Output disable time	t _{PLZ} ,t _{PHZ}		See Fig. 11.2.1, 11.2.2,	5.0 ± 0.5		4.5	
			Table 11.2.1	$\textbf{3.3}\pm\textbf{0.3}$		7	
				2.5 ± 0.2		9	
				1.8 ± 0.15	_	18	

11.4. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 125 °C)

Characteristics	Symbol	Note	Test Condition	V _{CC} (V)	Min	Max	Unit
Output enable time	t _{PZL} ,t _{PZH}		See Fig. 11.2.1, 11.2.2,	5.0 ± 0.5	_	6	ns
			Table 11.2.1	$\textbf{3.3}\pm\textbf{0.3}$		8	
				2.5 ± 0.2	—	11	
			1.8 ± 0.15		20		
Output disable time	t _{PLZ} ,t _{PHZ}		See Fig. 11.2.1, 11.2.2,	5.0 ± 0.5	_	6.5	
			Table 11.2.1	$\textbf{3.3}\pm\textbf{0.3}$	—	9	
			2.5 ± 0.2	_	11		
				1.8 ± 0.15		20	

11.5. Capacitive Characteristics (Note) (Unless otherwise specified, $T_a = 25$ °C)

Characteristics	Part Number	Symbol	Note	Test Condition	V _{CC} (V)	Тур.	Unit
Input capacitance (OE, OE)		C _{IN}		V _{IN} = 0 V	5.0	4	pF
Switch terminal OFF-	TC7WB66CFK	C _{I/O}		OE = GND, V _{I/O} = 0 V	5.0	5	
capacitance	TC7WB67CFK			$\overline{OE} = V_{CC}, V_{I/O} = 0 V$	5.0	5	
Switch terminal ON-	TC7WB66CFK	C _{I/O}		$OE = V_{CC}, V_{I/O} = 0 V$	5.0	10	
capacitance	TC7WB67CFK			\overline{OE} = GND, V _{I/O} = 0 V	5.0	10	

Note: Parameter guaranteed by design.

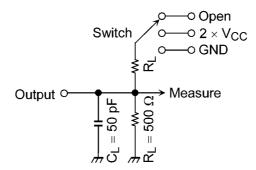


Fig. 11.2.1 AC Test Circuit



Parameter	Switch
t _{PLZ} , t _{PZL}	$2 \times V_{CC}$
t _{PHZ} , t _{PZH}	GND

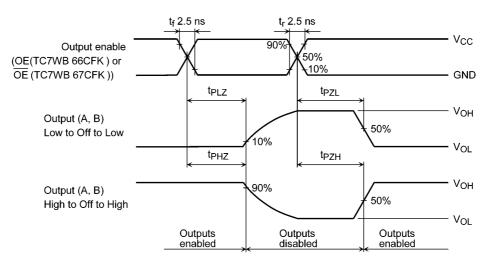


Fig. 11.2.2 AC Waveform tPLZ, tPHZ, tPZL, tPZH

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12. Rise and Fall Time (t_r/t_f)

The t_r and $t_{f(out)}$ values of the output signals are affected by the CR time constant of the input, which consists of the switch terminal capacitance ($C_{I/O}$) and the on-resistance (R_{ON}) of the input.

In practice, the t_r and $t_{f(out)}$ values are also affected by the circuit's capacitance and resistance components other than the capacitance of TC7WB66CFK, TC7WB67CFK

The $t_r\!/t_{f(out)}$ values can be approximated as follows.

(Figure 12.1, Table 12.1 shows the test circuit.)

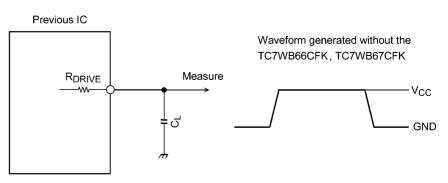
$$\label{eq:tr} \begin{split} t_r / t_{f(out)} \ (approx) = & \ (C_{I/O} + C_L) \ \cdot \ (R_{DRIVE} + R_{ON}) \ \cdot \ ln \ (((V_{OH} \cdot V_{OL}) \cdot V_M) \ / \ (V_{OH} \cdot V_{OL})) \end{split}$$
 Where, R_{DRIVE} is the output impedance of the previous-stage circuit.

Calculation example:

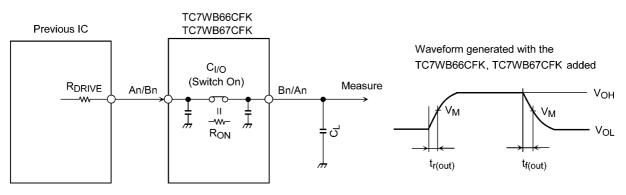
 $t_{r(out)} (approx) = -(10 + 15) E - 12 + (120 + 4) + ln (((4.5 - 0) - 2.25) / (4.5 - 0)) = \approx 2.1 ns$

Calculation conditions:

 V_{CC} = 4.5 V, C_L = 15 pF, R_{DRIVE} = 120 Ω (output impedance of the previous IC), V_M = 2.25 V (V_{CC} /2) Output of the previous IC = digital (i.e., high-level voltage = V_{CC} , low-level voltage = GND)



R_{DRIVE} = output impedance of the previous IC



R_{DRIVE} = output impedance of the previous IC

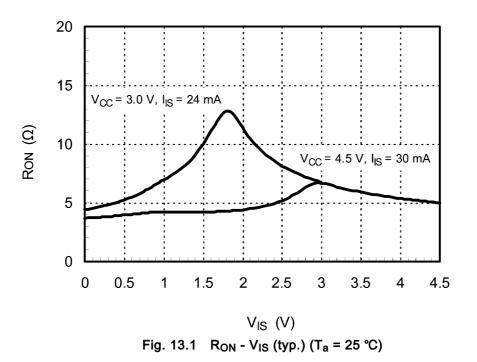
Fig. 12.1 Calculation Circuit

Table 1	2.1	Calculation	Circuit
	4 . I	Calculation	Oncure

Characteristics	V_{CC} = 5.0 \pm 0.5 V	V_{CC} = 3.3 \pm 0.3 V	V_{CC} = 2.5 \pm 0.2 V	V_{CC} = 1.8 \pm 0.15 V
V _M	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2

13. Characteristics Curves (Note)

TOSHIBA

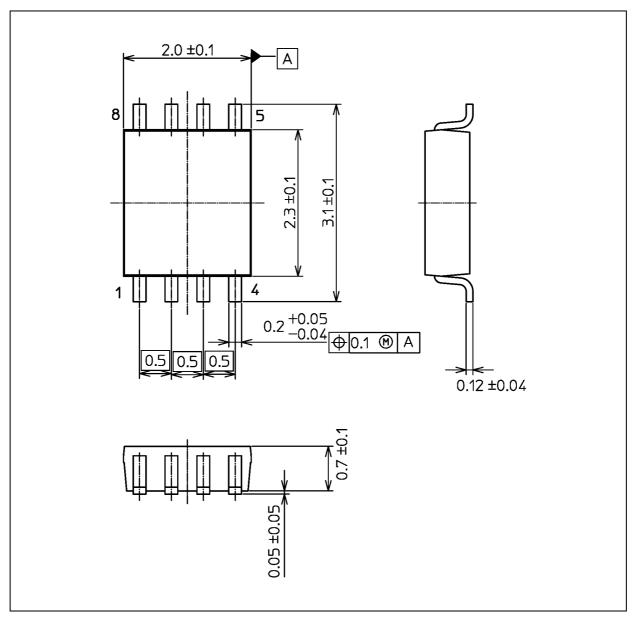


Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



Package Dimensions

Unit: mm



Weight: 0.01 g (typ.)

	Package Name(s)
JEDEC: SOT-765	
Nickname: US8	

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